

February 1990 Revised May 2005

MM74HCT573 • MM74HCT574 Octal D-Type Latch • 3-STATE Octal D-Type Flip-Flop

General Description

The MM74HCT573 octal D-type latches and MM74HCT574 octal D-type flip-flop advanced silicon-gate CMOS technology, which provides the inherent benefits of low power consumption and wide power supply range, but are LS-TTL input and output characteristic and pin-out compatible. The 3-STATE outputs are capable of driving 15 LS-TTL loads. All inputs are protected from damage due to static discharge by internal diodes to V_{CC} and ground.

When the MM74HCT573 Latch Enable input is HIGH, the Q outputs will follow the D inputs. When the Latch Enable goes LOW, data at the D inputs will be retained at the outputs until Latch Enable returns HIGH again. When a high logic level is applied to the Output Control input, all outputs go to a high impedance state, regardless of what signals are present at the other inputs and the state of the storage

The MM74HCT574 are positive edge triggered flip-flops. Data at the D inputs, meeting the setup and hold time requirements, are transferred to the Q outputs on positive going transitions of the Clock (CK) input. When a high logic level is applied to the Output Control (OC) input, all outputs go to a high impedance state, regardless of what signals are present at the other inputs and the state of the storage elements

The MM74HCT devices are intended to interface between TTL and NMOS components and standard CMOS devices. These parts are also plug in replacements for LS-TTL devices and can be used to reduce power consumption in existing designs.

Features

- TTL input characteristic compatible
- Typical propagation delay: 18 ns
- Low input current: 1 µA maximum
- Low quiescent current: 80 µA maximum
- Compatible with bus-oriented systems
- Output drive capability: 15 LS-TTL loads

Ordering Codes:

Order Number	Package Number	Package Description
MM74HCT573WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
MM74HCT573SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MM74HCT573MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HCT573N	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
MM74HCT574WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
MM74HCT574SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MM74HCT574MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HCT574N	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

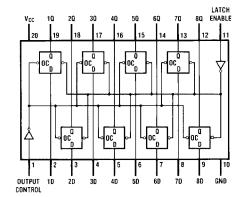
Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

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Connection Diagrams



Top View MM74HCT573

OUTPUT Control

Top View MM74HCT574

Truth Tables

MM74HCT573

Output Control	LE	Data	Output
L	Н	Н	Н
L	Н	L	L
L	L	Х	Q_0
Н	Х	Х	Z

H = HIGH Level

L= LOW Level
Q₀ = Level of output before steady-state input conditions were established.
Z = High Impedance State

MM74HCT574

Output Control	LE	Data	Output
L	↑	Н	Н
L	↑	L	L
L	L	Х	Q_0
Н	X	Х	Z

H = HIGH Level
L = LOW Level
Q₀ = Level of output before steady-state input conditions were established.

Z = High Impedance State

↑ = Transition from LOW-to-HIGH

Absolute Maximum Ratings(Note 1)

(Note 2)

Supply Voltage (V _{CC})	-0.5 to +7.0V
DC Input Voltage (V _{IN})	–1.5 to V _{CC} + 1.5V
DC Output Voltage (V _{OUT})	–0.5 to $V_{\rm CC}^+$ 0.5V
Clamp Diode Current (I _{IK} , I _{OK})	± 20 mA
DC Output Current, per pin (I _{OUT})	± 35 mA
DC V_{CC} or GND Current, per pin (I_{CC})	± 70 mA
Storage Temperature Range (T _{STG})	-65°C to +150°C
Power Dissipation (P _p)	

Power Dissipation (P_D) (Note 3)

S. O. Package only

Lead Temperature (T_L)

(Soldering 10 seconds) 260°C

Recommended Operating Conditions

	Min	Max	Units
Supply Voltage (V _{CC})	4.5	5.5	V
DC Input or Output Voltage			
(V_{IN}, V_{OUT})	0	V_{CC}	V
Operating Temperature Range (T _A)	-40	+85	°C
Input Rise or Fall Times			
t_r , t_f		500	ns
Note 1: Absolute Maximum Ratings are those	values b	eyond whi	ich dam-

age to the device may occur.

Note 2: Unless otherwise specified all voltages are referenced to ground.

Note 3: Power Dissipation temperature derating — plastic "N" package: –
12 mW/°C from 65°C to 85°C.

DC Electrical Characteristics

 $V_{CC} = 5V \pm 10\%$ (unless otherwise specified)

Symbol	Parameter	Conditions	$T_A = 25^{\circ}C$		T _A = -40 to 85°C	T _A = -55 to 125°C	Units	
Symbol		Conditions	Тур		Guaranteed Li	mits	Oillis	
V _{IH}	Minimum HIGH Level			2.0	2.0	2.0	V	
	Input Voltage							
V _{IL}	Maximum LOW Level			0.8	0.8	0.8	V	
	Input Voltage							
V _{OH}	Minimum HIGH Level	$V_{IN} = V_{IH}$ or V_{IL}						
	Output Voltage	$ I_{OUT} = 20 \mu A$	V_{CC}	V _{CC} - 0.1	V _{CC} - 0.1	V _{CC} - 0.1	V	
		$ I_{OUT} = 6.0 \text{ mA}, V_{CC} = 4.5 \text{V}$	4.2	3.98	3.84	3.7	V	
		$ I_{OUT} = 7.2 \text{ mA}, V_{CC} = 5.5V$	5.7	4.98	4.84	4.7		
V _{OL}	Maximum LOW Level	$V_{IN} = V_{IH}$ or V_{IL}						
	Voltage	$ I_{OUT} = 20 \mu A$	0	0.1	0.1	0.1	V	
		$ I_{OUT} = 6.0 \text{ mA}, V_{CC} = 4.5 \text{V}$	0.2	0.26	0.33	0.4	V	
		$ I_{OUT} = 7.2 \text{ mA}, V_{CC} = 5.5V$	0.2	0.26	0.33	0.4		
I _{IN}	Maximum Input	$V_{IN} = V_{CC}$ or GND,		±0.1	±1.0	±1.0	μА	
	Current	V_{IH} or V_{IL}						
l _{oz}	Maximum 3-STATE	V _{OUT} = V _{CC} or GND		±0.5	±5.0	±10	μΑ	
	Output Leakage	$Enable = V_{IH} \text{ or } V_{IL}$						
	Current							
I _{CC}	Maximum Quiescent	$V_{IN} = V_{CC}$ or GND		8.0	80	160	μΑ	
	Supply Current	$I_{OUT} = 0 \mu A$						
		V _{IN} = 2.4V or 0.5V (Note 4)		1.5	1.8	2.0	mA	

600 mW

500 mW

Note 4: Measured per pin. All others tied to V_{CC} or ground.

AC Electrical Characteristics MM74HCT573

 V_{CC} = 5.0V, t_r = t_f = 6 ns, T_A = 25°C (unless otherwise specified)

Symbol	Parameter	Conditions	Тур	Guaranteed Limit	Units
t _{PHL}	Maximum Propagation Delay	C _L = 45 pF	17	27	ns
t _{PLH}	Data to Output				
t _{PHL}	Maximum Propagation Delay	C _L = 45 pF	16	27	ns
t _{PLH}	Latch Enable to Output				
t _{PZH}	Maximum Enable Propagation Delay	C _L = 45 pF	21	30	ns
t_{PZL}	Control to Output	$R_L = 1 k\Omega$			
t _{PHZ}	Maximum Disable Propagation Delay	C _L = 5 pF	14	23	ns
t_{PLZ}	Control to Output	$R_L = 1 k\Omega$			
t _W	Minimum Clock Pulse Width			15	ns
t _S	Minimum Setup Time Data to Clock			5	ns
t _H	Minimum Hold Time Clock to Data			12	ns

AC Electrical Characteristics MM74HCT573

 $V_{CC} \! = 5.0 V \pm 10\%, \, t_{f} \! = t_{f} \! = \! 6 \, \text{ns}$ (unless otherwise specified)

Symbol	Parameter	Conditions	T _A	= 25 °	T _A = -40 to 85°C	T _A = -55 to 125°C	Units
Syllibol		Conditions	Тур	Guaranteed Limits			Oillis
t _{PHL}	Maximum Propagation	C _L = 50 pF	18	30	38	45	ns
t _{PLH}	Delay Data to Output						
t _{PHL}	Maximum Propagation Delay	C _L = 50 pF	17	30	44	53	ns
t _{PLH}	Latch Enable to Output						
t _{PZH}	Maximum Enable Propagation	C _L = 50 pF	22	30	38	45	ns
t _{PZL}	Delay Control to Output	$R_L=1\ k\Omega$					
t _{PHZ}	Maximum Disable Propagation	C _L = 50 pF	15	30	38	45	ns
t _{PLZ}	Delay Control to Output	$R_L=1\ k\Omega$					
t _{THL}	Maximum Output	C _L = 50 pF	6	12	15	18	ns
t _{TLH}	Rise and Fall Time						
t _W	Minimum Clock Pulse Width			15	20	24	ns
t _S	Minimum Setup Time Data to Clock		-3	5	6	8	ns
t _H	Minimum Hold Time Clock to Data		4	12	15	18	ns
C _{IN}	Maximum Input Capacitance			10	10	10	pF
C _{OUT}	Maximum Output Capacitance			20	20	20	pF
C _{PD}	Power Dissipation Capacitance	OC = V _{CC}		5			pF
	(Note 5)	OC = GND		52			

Note 5: C_{PD} determines the no load dynamic power consumption, P_D = C_{PD} V_{CC}2 f+I_{CC} V_{CC}, and the no load dynamic current consumption, I_S = C_{PD} V_{CC} f+I_{CC}.

AC Electrical Characteristics MM74HCT574

 $V_{CC} = 5.0V$, $t_r = t_f = 6$ ns, $T_A = 25$ °C

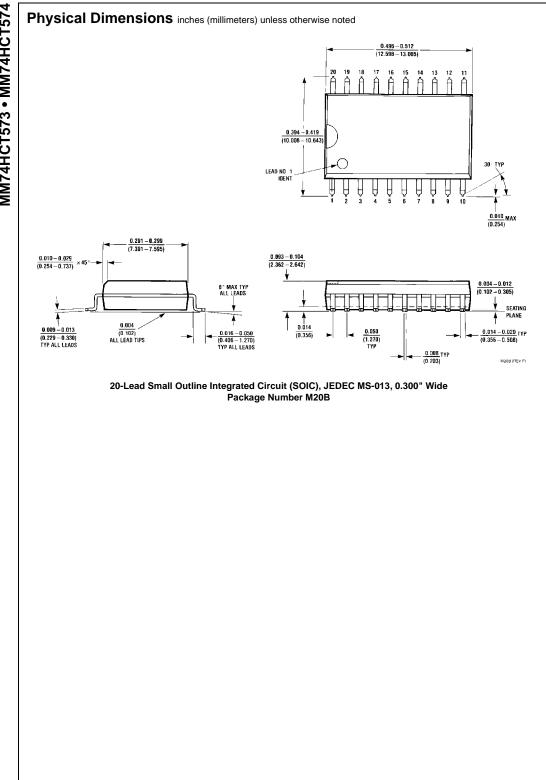
Symbol	Parameter	Conditions	Тур	Guaranteed Limit	Units
f _{MAX}	Maximum Clock Frequency		60	33	MHz
t _{PHL}	Maximum Propagation Delay	C _L = 45 pF	17	27	ns
t_{PLH}	to Output				
t _{PZH}	Maximum Enable Propagation Delay	C _L = 45 pF	19	28	ns
t_{PZL}	Control to Output	$R_L = 1 k\Omega$			
t _{PHZ}	Maximum Disable Propagation Delay	C _L = 45 pF	14	25	ns
t_{PLZ}	Control to Output	$R_L = 1 k\Omega$			
t _W	Minimum Clock Pulse Width			15	ns
t _S	Minimum Setup Time Data to Clock			12	ns
t _H	Minimum Hold Time Clock to Data			5	ns

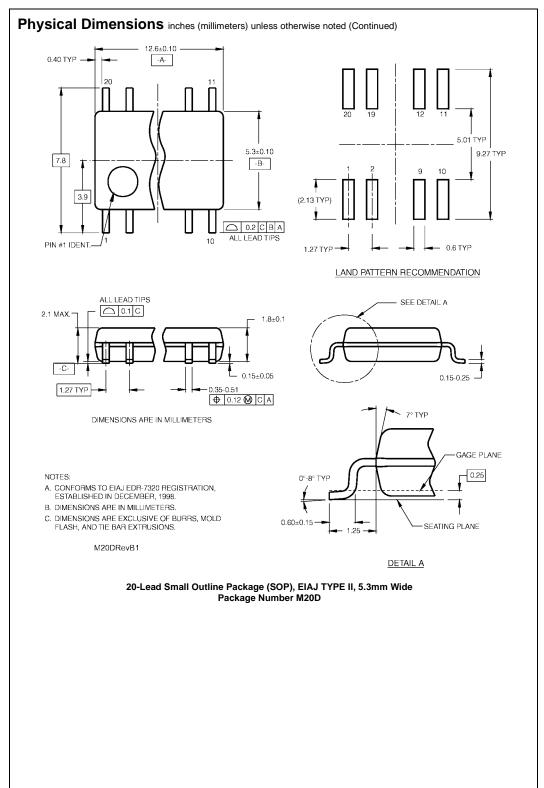
AC Electrical Characteristics MM74HCT574

 $V_{CC} = 5.0V \pm 10\%$, $t_r = t_f = 6$ ns (unless otherwise specified)

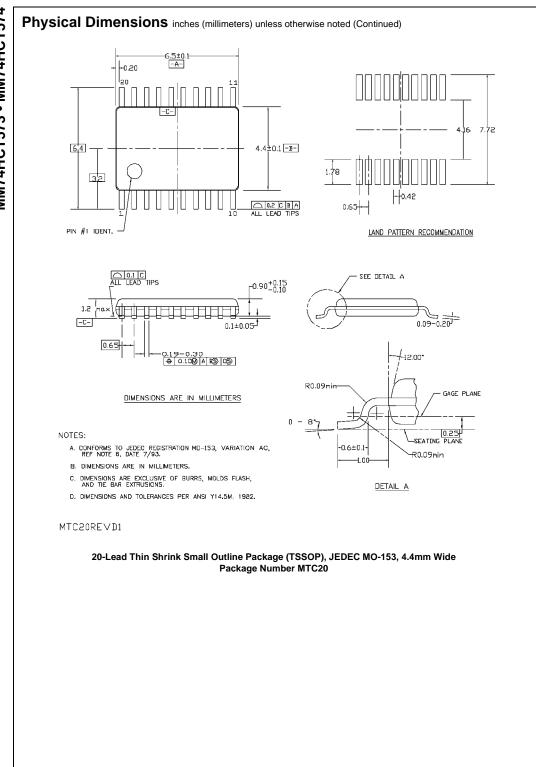
Symbol	Parameter	Conditions	T _A = 2	$T_A = 25^{\circ}C$ $T_A = -40 \text{ to } 85^{\circ}C$ $T_A = -55 \text{ to } 125^{\circ}C$		T _A = -55 to 125°C	Units
Cymbol			Тур		Guaranteed	Limits	Oillio
f _{MAX}	Maximum Clock Frequency			33	28	23	MHz
t _{PHL}	Maximum Propagation Delay	C _L = 50 pF	18	30	38	45	ns
t _{PLH}	Clock to Output						
t _{PZH}	Maximum Enable Propagation	C _L = 50 pF	22	30	38	45	ns
t_{PZL}	Delay Control to Output	$R_L = 1 \ k\Omega$					
t _{PHZ}	Maximum Disable Propagation	C _L = 50 pF	15	30	38	45	ns
t_{PLZ}	Delay Control to Output	$R_L = 1 k\Omega$					
t _{THL}	Maximum Output	C _L = 50 pF	6	12	15	18	ns
t _{TLH}	Rise and Fall Time						
t _W	Minimum Clock Pulse Width			15	20	24	ns
t _S	Minimum Setup Time Data to Clock		6	12	15	18	ns
t _H	Minimum Hold Time Clock to Data		-1	5	6	8	ns
C _{IN}	Maximum Input Capacitance			10	10	10	pF
C _{OUT}	Maximum Output Capacitance			20	20	20	pF
C _{PD}	Power Dissipation Capacitance	$OC = V_{CC}$	5				pF
	(Note 6)	OC = GND	58				

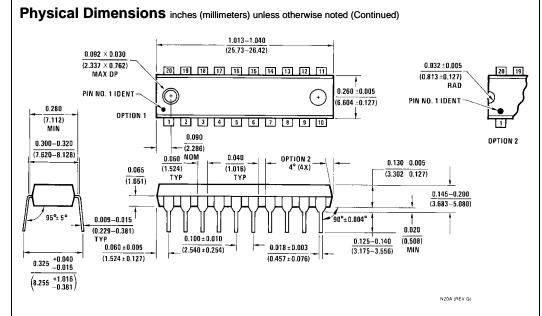
Note 6: C_{PD} determines the no load power consumption, $P_D = C_{PD} \ V_{CC}^2 \ f + I_{CC} \ V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD} \ V_{CC} \ f + I_{CC}$.





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20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide Package Number N20A

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